Massive Dirac Fermion at the Surface of the van der Waals Antiferromagnet MnBi$_2$Te$_4$

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The layered van der Waals compound MnBi$_2$Te$_4$ has been predicted to combine the band ordering of archetypical topological insulators like Bi$_2$Te$_3$ with the magnetism of Mn, making this material a viable candidate for the realization of various magnetic topological states. We have systematically investigated the surface electronic structure of MnBi$_2$Te$_4$(0001) single crystals by use of angle-resolved photoelectron spectroscopy (ARPES) experiments. Combining photon-energy-dependent and spin-resolved measurements we establish the presence of a single massive Dirac fermion at the MnBi$_2$Te$_4$(0001) surface, both, in the low-temperature antiferromagnetic phase and in the paramagnetic phase. Our experimental results establish the coexistence of a topological surface state and magnetic order in MnBi$_2$Te$_4$.

The hallmark of a topological insulator is a single spin-polarized Dirac cone at the surface which is protected by time reversal-symmetry and originates from a band inversion in the bulk [1, 2]. Notably, breaking time-reversal symmetry by magnetic order does not necessarily destroy the non-trivial topology but instead may drive the system into another topological phase. One example is the quantum anomalous Hall (QAH) state that has been observed in magnetically doped topological insulators [3]. The QAH state, in turn, may form the basis for yet more exotic electronic states, such as axion insulators [4, 5] and chiral Majorana fermions [6]. Another example is the antiferromagnetic topological insulator state which is protected by a combination of time-reversal and lattice translational symmetries [7].

Magnetic order in a topological insulator has mainly been achieved by doping with 3d impurities [8, 9], which however inevitably gives rise to increased disorder. By contrast, the layered van der Waals material MnBi$_2$Te$_4$ [8,9,10] has recently been proposed to realize an intrinsic magnetic topological insulator [11–14], i.e. a compound that features magnetic order and a topologically non-trivial bulk band structure at the same time. MnBi$_2$Te$_4$ is isostructural to the known topological insulators GeBi$_2$Te$_4$ [15,17] and PbBi$_2$Te$_4$ [18], but the substitution of Ge or Pb by Mn introduces local magnetic moments
which order antiferromagnetically below \( \sim 24 \text{K} \). The resulting interplay of magnetic order and topology in a single compound has been proposed as a promising platform for the realization of a variety of magnetic topological states.

In this work we present a systematic investigation of the surface electronic structure in MnBi\(_2\)Te\(_4\) (0001) single crystals employing angle-resolved photoelectron spectroscopy (ARPES), spin-resolved ARPES and resonant photoemission at the Mn \( L \)-edge. Our measurements reveal a surface state in the bulk band gap that forms a spin-polarized massive Dirac cone in agreement with recent theoretical predictions. The large mass-induced gap of \( \sim 100 \text{meV} \) is robust across the transition from the antiferromagnetic phase into the paramagnetic phase, which we distinguish by X-ray magnetic circular dichroism (XMCD and XMLD) experiments. Our results establish the existence of a topologically non-trivial surface state in a pristine, magnetic compound, and corroborate that MnBi\(_2\)Te\(_4\) realizes an intrinsically magnetic topological insulator.

The ARPES measurements were performed at the MAESTRO [Fig. 1(a), 2(a)-(e), Fig. S2] and Merlin [Fig. 3(c)] endstations of the Advanced Light Source (USA) as well as at beamline I05 of the Diamond Light Source (UK) [Fig. 3(a)-(b)]. The energy resolution of the ARPES experiments was better than 20 meV. Spin-resolved ARPES measurements were performed at the APE beamline of the Elettra synchrotron by use of a Scienta DA30 hemispherical analyser combined with a spin polarimeter based on very low-energy electron diffraction (Sherman function \( S = 0.3 \)). We acquired XMCD and XMLD data in total electron yield (TEY) mode at the BOREAS beamline of the ALBA Synchrotron (Spain). Resonant soft X-ray photoemission data and Mn 2p core-level spectra were collected at the ASPHERE III endstation at beamline P04 of PETRA III (Germany) with an energy resolution of ca. 25 meV. Platelet-like MnBi\(_2\)Te\(_4\) single crystals were obtained via an optimized crystal-growth procedure as described in Ref. [19]. MnBi\(_2\)Te\(_4\) crystallizes in a trigonal lattice (the ordered GeAs\(_2\)Te\(_4\) structure type) with septuple [Te-Bi-Te-Mn-Te-Bi-Te] layers stacked in the \( \text{ABC} \) fashion. The septuple layers are separated by a van der Waals gap, as shown in Fig. 1(b). Our X-ray single-crystal study confirms the structure motif plus a certain degree of Mn/Bi antisite intermixing in both cation positions [19]. Mn atoms are ordered in definite crystallographic sites in a periodic crystal lattice in contrast to doped topological insulators. Cleavage of single crystals exposes well-ordered (0001) surfaces suitable for surface sensitive experiments. From an inspection of the Mn 2p core-level line shapes in X-ray photoemission and absorption (XPS and XAS) in Fig. 1(c) and Fig. S1 we infer a \( 3d^5 \) configuration of the Mn ions (Mn\(^{2+}\)) [23, 24]. Magnetic susceptibility measurements of bulk MnBi\(_2\)Te\(_4\) imply an antiferromagnetic ground state below \( T_N = 24 \text{K} \) [19, 21]. Furthermore, they indicate an out-of-plane orientation of the magnetic moments with ferromagnetic intralayer coupling and antiferromagnetic interlayer coupling. This is in agreement with first-principles calculations [11, 13] and fully supported by our XMCD and XMLD measurements [see Fig. S1 in the supplemental material].

Figure 1(a) presents an ARPES data set for MnBi\(_2\)Te\(_4\) (0001) close the Fermi level \( E_F \). The data bear strong similarities to those obtained previously for isostructural GeBi\(_2\)Te\(_4\) (0001) [15, 17], and show a state with Dirac-like band dispersion at the \( \Gamma \)-point, see also Figs. 2 and 3. In contrast to GeBi\(_2\)Te\(_4\) (0001), however, our data provide evidence for an energy splitting between the upper and the lower part of the Dirac cone (UDC and LDC). The measured dispersion in Fig. 1(a), including the size of the splitting of \( \sim 100 \text{meV} \) at \( \bar{\Gamma} \), is in good agreement with previous first-principles theory for antiferromagnetic MnBi\(_2\)Te\(_4\) [11, 13] and for a single, ferromagnetic MnBi\(_2\)Te\(_4\) septuple layer on Bi\(_2\)Te\(_3\) (0001) [25]. These calculations predict the presence of a spin-polarized Dirac surface state with a gap in the magnetically ordered state.

A more detailed analysis of the electronic band structure is presented in Figs. 2(a)-(c). Besides the UDC, which shows a narrow line shape typical for surface states, we observe...
FIG. 2: (color online) (a) ARPES constant energy contours for MnBi$_2$Te$_4$(0001). At the Fermi level a hexagonal warping of the UDC and a flower-like pattern of the bulk conduction band (BCB) is observed. (b)-(c) ARPES data sets along the ΓM- and ΓK-directions. (d)-(e) Photon-energy-dependent data for the UDC and LDC ($T = 18$ K). (f) Schematic of the experimental geometry for the spin-resolved measurements. (g)-(h) Spin-resolved momentum- and energy distribution curves obtained for a spin-quantization axis along $y$, i.e. in-plane and perpendicular to the probed wave vector along $k_x$. The reversal of the spin polarization of the UDC at $\pm k_x$ indicates a helical spin configuration. All data sets except for (d)-(e) were acquired with $h\nu = 21.5$ eV and at $T = 80$ K.

more diffuse features close to the Fermi level which we attribute to the bottom of the bulk conduction band (BCB). One BCB feature is centered at the $\bar{\Gamma}$-point in between the UDC branches, which has been observed similarly in n-doped topological insulators like Bi$_2$Te$_3$ [20]. Furthermore, we find additional BCB features at finite wave vectors along the ΓM direction which form a flower-like pattern in the Fermi surface and partly overlap with the UDC. This characteristic shape of the conduction band minimum poses an important constraint for theoretical approaches. We note that similar pockets at finite wave vectors along Γ have been observed for GeBi$_2$Te$_4$(0001) [17].

In order to investigate the dimensionality of the massive Dirac state we performed photon-energy-dependent ARPES measurements [Fig. 2(d)-(e) and Fig. S2 in the supplement]. We find that the dispersion of the UDC and the LDC both show no significant variation over the measured photon-energy range between $h\nu = 20$-24 eV. While generally this observation is consistent with a surface origin of these features, we note that, according to previous calculations, also the bulk states at the valence band maximum and the conduction band minimum have a markedly two-dimensional character with very small dispersion along $k_x$ [11-13]. Although this hampers an unambiguous assignment, comparing our data to the calculated band structure [11] suggests a surface origin of the UDC and a mixed surface and bulk-valence-band character of the LDC. This situation is reminiscent of related topological insulators like Bi$_2$Se$_3$ [27].

A key property of the Dirac surface state in a topological insulator is a high degree of spin polarization. Our spin-resolved ARPES data in Fig. 2(g)-(h) indeed confirm a spin polarization of the UDC. As sketched in Fig. 2(f), the spin-polarized data were obtained at wave vectors along $k_x$ with a spin-quantization axis along $y$. The p-polarized light was incident in the $yz$ plane. In particular, the energy distribution curve at $k_x = 0.04$ Å$^{-1}$ in Fig. 2(h) provides evidence for a high spin polarization of the UDC. At $k_x = -0.06$ Å$^{-1}$ the spin polarization of the UDC is reversed as expected for a spin-momentum-locked state, but also significantly reduced. We attribute the reduction in spin polarization at this wave vector to a stronger overlap and potential hybridization of the UDC with the BCB. The reversal of the spin polarization at $\pm k_x$ is also observed in the spin-resolved momentum distribution curve in Fig. 2(g).

Collectively, these results provide strong experimental evidence for a spin-polarized massive Dirac state at the surface of MnBi$_2$Te$_4$(0001). To study the origin of the splitting of the Dirac cone, we compare ARPES data sets obtained below and above the antiferromagnetic ordering temperature $T_N = 24$ K.
in Fig. 3. Apparently, the dispersion shows no pronounced changes when passing from the antiferromagnetic into the paramagnetic state. The EDC taken at the \( \Gamma \) point suggest a slight shift of both the UDC and LDC to higher binding energy for lower \( T \), but there is no significant change in the size of the splitting above \( T_N \).

The lack of a temperature dependence up to substantially above \( T_N \) indicates that the splitting of the Dirac cone does not originate from long-range magnetic order with out-of-plane magnetization, as was expected based on previous calculations for MnBi\(_2\)Te\(_4\) \([12, 14, 25, 28]\) and other materials \([29, 32]\). However, the paramagnetic state has not been considered in these works. Despite this discrepancy we note that the size of the measured splitting is of similar magnitude as those predicted theoretically for magnetically ordered MnBi\(_2\)Te\(_4\) \([11–13]\). This suggests that the coupling strength between the surface state and the magnetic moments of Mn is generally sufficient to induce a splitting of up to 100 meV as observed experimentally. We note that also in other systems a gap in the Dirac cone was observed in the paramagnetic regime, including Fe- and Mn-doped Bi\(_2\)Se\(_3\) \([9, 33, 34]\). Similar findings were also obtained for TlBi\(_2\)(Se\(_x\)S\(_{1−x}\))\(_2\) \([35]\).

Overall, our finding of a massive Dirac cone on the MnBi\(_2\)Te\(_4\)(0001) surface is in agreement with several first-principles theory studies, which unanimously predict that the bulk band structure of MnBi\(_2\)Te\(_4\) \([11, 13]\) and also MnBi\(_2\)Se\(_4\) \([36, 37]\) is topologically non-trivial. A potential concern here is that an accurate description of the localized Mn 3\(d\) orbitals is not readily expected in calculations based on density functional theory (DFT) and could play an essential role \([38]\).

To assess the character of the Mn 3\(d\) states we have carried out resonant photoemission experiments at the \( L_{2,3} \) absorption edge [Fig. 4]. The measured Mn density of states (DOS) shows a state at ca. 3.8 eV and another one at ca. 0.8 eV that is attributed to hybridization between Mn 3\(d\) and Te 5\(p\) orbitals near the top of the valence band, which is in rather good agreement with DFT \([8]\). This result suggests that these calculations capture the energetics of the Mn 3\(d\) states reasonably well and thus substantiates the topological classification.

The persistence of the gap above \( T_N \), however, calls for further theoretical investigation. In general, the protection of the Dirac point in a topological insulator is based on the absence of backscattering due to destructive interference between scattering channels related by time-reversal symmetry. A recent theory shows that, if this destructive interference is perturbed, strong impurity scattering may induce gap features at the Dirac point of similar size as observed here for MnBi\(_2\)Te\(_4\) \([39]\). Notably, single magnetic Mn impurities placed in the topological insulator Bi\(_2\)Te\(_3\) have been found to constitute strong scattering centers for the topological surface state \([40]\).

FIG. 3: (color online) (a)-(b) Temperature-dependent ARPES data for MnBi\(_2\)Te\(_4\)(0001) below and above \( T_N \) measured with \( h\nu = 21.5 \) eV along \( \Gamma M \). (c) Energy distribution curves (EDC) at \( k_\parallel = 0 \).
Therefore, based on our results we anticipate that the local magnetic moments in the Mn layers in MnBi$_2$Te$_4$ may allow for backscattering processes and thereby destroy the topological protection of the Dirac point. A rather local nature of the Mn states in MnBi$_2$Te$_4$ is supported by the measured 3$d$ DOS in Fig. 5 that resembles the one of single Mn impurities in Sb$_2$Te$_3$ [41].

In summary, our experiments unveil a topologically non-trivial surface electronic structure of the antiferromagnet MnBi$_2$Te$_4$(0001). In particular, MnBi$_2$Te$_4$ provides a first instance of a material that features a massive Dirac surface state and relies neither on doping nor alloying. Our results could provide new pathways to exploit the interplay of antiferromagnetism and topological edge states in spintronic device concepts based on the emerging material class of van der Waals magnets [42].

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